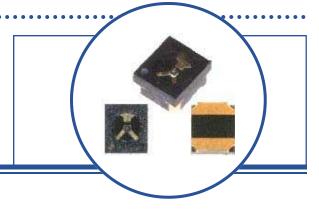
## **Infrared Light Emitting VCSEL OPR2800V**



#### Features:

- High speed VCSEL
- · High output power
- · Narrow beam angle
- Suitable for all types of high-speed data communications equipment
- Also available as diode (OPR2800, OPR2800T)



#### **Description:**

The OPR2800V is a high performance 850 nm invisible VCSEL (Class 1M) with a flat lens window. Its high speed, high output power and concentric beam pattern make it an ideal transmitter for all types of high-speed data equipment applications.

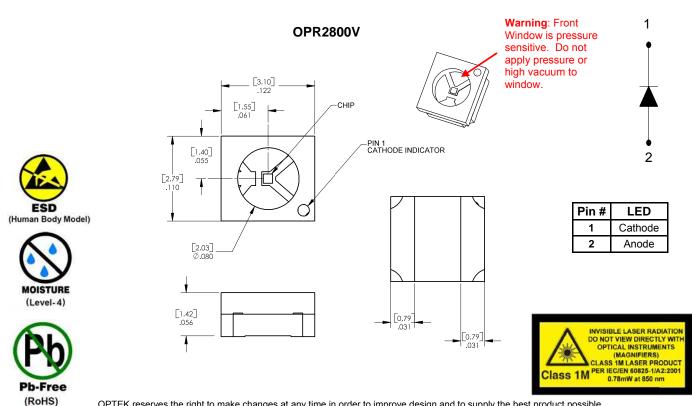
Please refer to Application Bulletins 221 and 224 for additional design information and reliability (degradation) data.

Refer to Application Bulletin 237

### **Applications:**

- Fibre channel
- Gigabit Ethernet
- ATM
- VSR (Very Short Reach)
- Intra-system links
- Optical backplane interconnects

Ordering Information						
Part Number	LED Peak Wavelength	Total Beam Angle	Laser Class	Packaging		
OPR2800V	850 nm	24°	Class 1M	Chip Tray		



OPTEK reserves the right to make changes at any time in order to improve design and to supply the best product possible.

# Infrared Light Emitting VCSEL OPR2800V



## Absolute Maximum Ratings (T<sub>A</sub> = 25° C unless otherwise noted)

Storage Temperature Range	-40° C to +100° C
Operating Temperature Range	0° C to +85° C
Maximum Forward Peak Current	20 mA
Maximum Reverse Voltage	10 V
Maximum Continuous Optical Power at 70° C	1.1 mW
Solder reflow time within 5°C of peak temperature is 20 to 40 seconds	250° C <sup>(1)</sup>

#### Notes:

#### **Electrical Characteristics** (T<sub>A</sub> = 25° C unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
$V_{F}$	Forward Voltage	1.60	-	2.20	V	I <sub>F</sub> = 7 mA
I <sub>R</sub>	Reverse Current	-	-	35	μA	-
t <sub>r,</sub> t <sub>f</sub>	Output Rise Time, Output Fall Time	-	100	-	ps	20% to 80%
P <sub>OT</sub>	Total Power Out	1.50	-	-	mW	I <sub>F</sub> = 7 mA
I <sub>TH</sub>	Threshold Current <sup>(1)</sup>	0.80	-	3	mA	
Rs	Series Resistance <sup>(2)</sup>	20	-	55	ohms	
η	Slope Efficiency <sup>(3)</sup>	0.28	-	-	mW/mA	
-	Linearity <sup>(4)</sup>	0.00	-	-	-	
$\lambda_{P}$	Wavelength at Peak Emission	840	850	860	nm	-
Δλ	Optical Bandwidth	-	-	0.85	nm	-
θ	Beam Divergence	-	24	-	Degree	I <sub>F</sub> = 7 mA
N <sub>RI</sub>	Relative Intensity Noise	-	-123	-	db/Hz	-
ΔΙ <sub>ΤΗ</sub> /ΔΤ	Temp Coefficient of Threshold Current	-	±1.0	-	mA	0° - 70° <sup>(1)</sup>
Δλ/ΔΤ	Temp Coefficient of Wavelength	-	0.06	-	%/°C	0° - 70°, I <sub>F</sub> = 7 mA
$\Delta V_F/\Delta T$	Temperature Coefficient for V <sub>F</sub>	-	-2.5	-	mW%/°C	0° - 70°, I <sub>F</sub> = 7 mA
Δη/ΔΤ	Temperature Coefficient for Efficiency <sup>(3)</sup>	-	-0.5	-	%/C	0° - 70°

#### Notes:

- 1. Threshold current is based on the two line intersection method specified in Telcordia GR468-Core. Line 1 from 4 mA to 6mA. Line 2 from 0 mA to 0.5 mA.
- 2. Series resistance is the slope of the voltage-current line from 5 to 8 mA.
- 3. Slope efficiency is the slope of the best-fit LI line from 5 mA to 8 mA, using no larger than 0.25 mA test interval points.
- 4. Using data points taken for slope efficiency above, ΔL/ ΔI shall be calculated for each adjacent pair of points.

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<sup>1.</sup> Solder time less than 5 seconds at temperature extreme.



## OP2800V - Normalized Output Power vs Forward Current

